

Vishay Semiconductors

# Medium Power Silicon Rectifier Diodes, (Stud Version), 12 A



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	12 A			
Package	DO-4 (DO-203AA)			
Circuit configuration	Single			

#### **FEATURES**

- Voltage ratings from 50 V to 1000 V
- · High surge capability



- Low thermal impedance
- High temperature rating
- Can be supplied as JAN and JAN-TX devices in accordance with MIL-S-19500/260
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I <sub>F(AV)</sub>		12	A	
	T <sub>C</sub>	150	°C	
I <sub>FSM</sub>	50 Hz	230	^	
	60 Hz	240	Α	
I <sup>2</sup> t	50 Hz	260	A <sup>2</sup> s	
	60 Hz	240	A-5	
T <sub>J</sub>		-65 to +200	°C	
V <sub>RRM</sub>	Range	50 to 1000	V	

#### Note

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RA	VOLTAGE RATINGS				
TYPE NUMBER	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	V <sub>R(RMS)</sub> , MAXIMUM RMS REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	V <sub>RM</sub> , MAXIMUM DIRECT REVERSE VOLTAGE (T <sub>C</sub> = -65 °C TO 200 °C) V	
VS-1N1199A	50	35	100	50	
VS-1N1200A	100	70	200	100	
VS-1N1201A	150	105	300	150	
VS-1N1202A	200	140	350	200	
VS-1N1203A	300	210	450	300	
VS-1N1204A	400	280	600	400	
VS-1N1205A	500	350	700	500	
VS-1N1206A	600	420	800	600	
VS-1N3670A	700	490	900	700	
VS-1N3671A	800	560	1000	800	
VS-1N3672A	900	630	1100	900	
VS-1N3673A	1000	700	1200	1000	
VS-1N3624	1000	1200	1400	1000	

#### Notes

- JEDEC® registered values are in bold
- Basic part number indicates cathode to case; for anode to case, add "R" to part number, e.g., 1N1199RA

JEDEC® registered values are in bold



### www.vishay.com

# Vishay Semiconductors

FORWARD COM	IDUCTION					
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at case temperature		I <sub>F(AV)</sub>	180° sinusoidal conduction		12	Α
		·F(AV)	Too sinassiaa sonaasiisi		150	°C
Maximum peak one cycle non-repetitive surge current		I <sub>FSM</sub>	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	230	
			Half cycle 60 Hz sine wave or 5 ms rectangular pulse		240	
			Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load	275	
			Half cycle 60 Hz sine wave or 5 ms rectangular pulse	condition and with V <sub>RRM</sub> applied following surge = 0 V	285	
			t = 10 ms	With rated V <sub>RRM</sub> applied	260	
Maximum I <sup>2</sup> t for fusin	Maximum I <sup>2</sup> t for fusing		t = 8.3 ms	following surge, initial T <sub>J</sub> = 200 °C	240	A <sup>2</sup> s
Maximum I2t for indiv	Maximum I <sup>2</sup> t for individual		t = 10 ms	With V <sub>RRM</sub> = 0 V following	370	
device fusing			t = 8.3 ms	surge, initial T <sub>J</sub> = 200 °C	340	]
Maximum I <sup>2</sup> √t for indi device fusing	Maximum I <sup>2</sup> √t for individual device fusing		t = 0.1 ms to 10 ms, V <sub>RRM</sub> = 0 V following surge		3715	A²√s
Maximum forward voltage drop		$V_{FM}$	I <sub>F(AV)</sub> = 12 A (38 A peak), T <sub>C</sub> = 25 °C		1.35	V
	V <sub>RRM</sub> = 50 V		· · · · · · · · · · · · · · · · · · ·		3.0	
	V <sub>RRM</sub> = 100 V				2.5	
	V <sub>RRM</sub> = 150 V				2.25	]
	$V_{RRM} = 200 \text{ V}$	I <sub>R(AV)</sub> <sup>(2)</sup>	Maximum rated $I_{F(AV)}$ and $T_{C}$		2.0	mA
Maximum average reverse current	V <sub>RRM</sub> = 300 V				1.75	
	V <sub>RRM</sub> = 400 V				1.5	
	$V_{RRM} = 500 \text{ V}$				1.25	
	$V_{RRM} = 600 \text{ V}$				1.0	
	$V_{RRM} = 700 \text{ V}$				0.9	
	$V_{RRM} = 800 \text{ V}$				8.0	
	V <sub>RRM</sub> = 900 V				0.7	-
	V <sub>RRM</sub> = 1000 V				0.6	

#### Notes

- JEDEC® registered values are in bold
- (1)  $I^2t$  for time  $t_x = I^2\sqrt{t} \times \sqrt{t_x}$
- (2) Maximum peak reverse current ( $I_{RM}$ ) under same conditions  $\approx 2 \text{ x rated } I_{R(AV)}$

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum operating ca storage temperature ra		T <sub>C</sub> , T <sub>Stg</sub>		-65 to 200	°C
Maximum internal thermal resistance, junction to case		$R_{thJC}$	DC operation	2.0	°C/W
Thermal resistance, case to sink		R <sub>thCS</sub>	Mounting surface, smooth, flat and greased 0.5		
	minimum		Torque applied to nut; non-lubricated threads	1.36 (12)	N · m (lbf · in)
	maximum			1.69 (15)	
Mounting torque	minimum		Tarana analiad ta mutulularia ataul thuasada	1.07 (9.45)	
Mounting torque	maximum		Torque applied to nut; lubricated threads	1.30 (11.55)	
	minimum		Torque applied to device case; lubricated threads	1.17 (10.35)	
	maximum			1.43 (12.65)	
Approximate weight				7.0	g
				0.25	OZ.
Case style			JEDEC® DO-4 (DO-203A		D-203AA)

#### Note

• JEDEC registered values are in bold

#### www.vishay.com

## Vishay Semiconductors

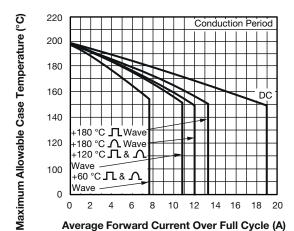


Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature

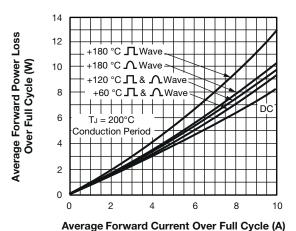


Fig. 2 - Maximum Low Level Forward Power Loss vs. Average Forward Current

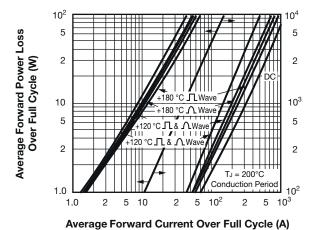


Fig. 3 - Maximum High Level Forward Power Loss vs. Average Forward Current

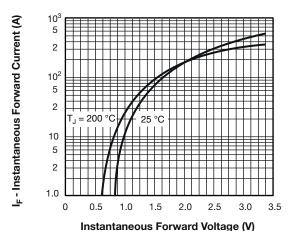


Fig. 4 - Maximum Forward Voltage vs. Forward Current

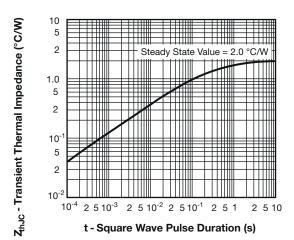


Fig. 5 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration

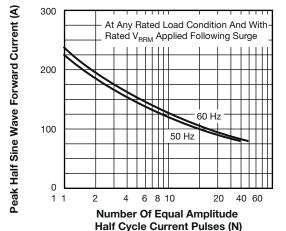


Fig. 6 - Maximum Non-Repetitive 50 Hz Surge Current vs. Number of Current Pulses

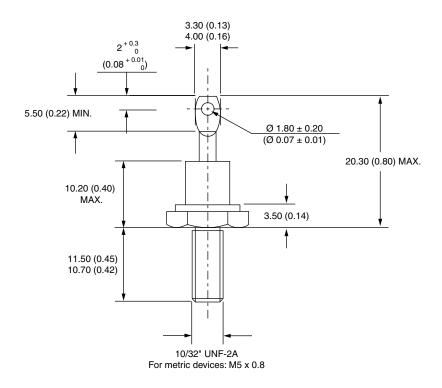
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95311	

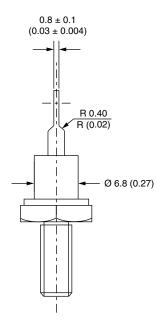


## Vishay Semiconductors

# DO-203AA (DO-4)

### **DIMENSIONS** in millimeters (inches)







## **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.